

Standard Rectifier Module

$$V_{RRM} = 2 \times 1600 \text{ V}$$

$$I_{FAV} = 35 \text{ A}$$

$$V_F = 1.1 \text{ V}$$

Phase leg

Part number

MDMA35P1600TG



Backside: isolated

 E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Height: 30 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

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Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V_{RSM}	max. non-repetitive reverse blocking voltage					1700	V
V_{RRM}	max. repetitive reverse blocking voltage					1600	V
I_R	reverse current	$V_R = 1600$ V		$T_{VJ} = 25^\circ\text{C}$		20	μA
		$V_R = 1600$ V		$T_{VJ} = 150^\circ\text{C}$		1.5	mA
V_F	forward voltage drop	$I_F = 35$ A		$T_{VJ} = 25^\circ\text{C}$		1.15	V
		$I_F = 70$ A				1.34	V
		$I_F = 35$ A		$T_{VJ} = 125^\circ\text{C}$		1.10	V
		$I_F = 70$ A				1.35	V
I_{FAV}	average forward current	$T_C = 100^\circ\text{C}$	rectangular	$T_{VJ} = 150^\circ\text{C}$		35	A
V_{FO}	threshold voltage	} for power loss calculation only				0.83	V
r_F	slope resistance					7.3	m Ω
R_{thJC}	thermal resistance junction to case					0.9	K/W
R_{thCH}	thermal resistance case to heatsink			0.2			K/W
P_{tot}	total power dissipation			$T_C = 25^\circ\text{C}$		130	W
I_{FSM}	max. forward surge current	$t = 10$ ms; (50 Hz), sine		$T_{VJ} = 45^\circ\text{C}$		500	A
		$t = 8,3$ ms; (60 Hz), sine		$V_R = 0$ V		540	A
		$t = 10$ ms; (50 Hz), sine		$T_{VJ} = 150^\circ\text{C}$		425	A
		$t = 8,3$ ms; (60 Hz), sine		$V_R = 0$ V		460	A
I^2t	value for fusing	$t = 10$ ms; (50 Hz), sine		$T_{VJ} = 45^\circ\text{C}$		1.25	kA ² s
		$t = 8,3$ ms; (60 Hz), sine		$V_R = 0$ V		1.22	kA ² s
		$t = 10$ ms; (50 Hz), sine		$T_{VJ} = 150^\circ\text{C}$		905	A ² s
		$t = 8,3$ ms; (60 Hz), sine		$V_R = 0$ V		880	A ² s
C_J	junction capacitance	$V_R = 400$ V; $f = 1$ MHz		$T_{VJ} = 25^\circ\text{C}$		19	pF



Package TO-240AA		Ratings				
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			200	A
T_{VJ}	virtual junction temperature		-40		150	°C
T_{op}	operation temperature		-40		125	°C
T_{stg}	storage temperature		-40		125	°C
Weight				76		g
M_D	mounting torque		2.5		4	Nm
M_T	terminal torque		2.5		4	Nm
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	13.0	9.7		mm
$d_{Spb/Apb}$		terminal to backside	16.0	16.0		mm
V_{ISOL}	isolation voltage	t = 1 second		4800		V
		t = 1 minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	4000		V



Part description

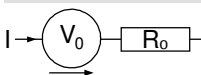
- M = Module
- D = Diode
- M = Standard Rectifier
- A = (up to 1800V)
- 35 = Current Rating [A]
- P = Phase leg
- 1600 = Reverse Voltage [V]
- TG = TO-240AA

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDMA35P1600TG	MDMA35P1600TG	Box	36	515014

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 150^{\circ}C$



Rectifier

$V_{0\ max}$	threshold voltage	0.83	V
$R_{0\ max}$	slope resistance *	6.1	mΩ



Outlines TO-240AA



General tolerance: DIN ISO 2768 class „c“





Rectifier

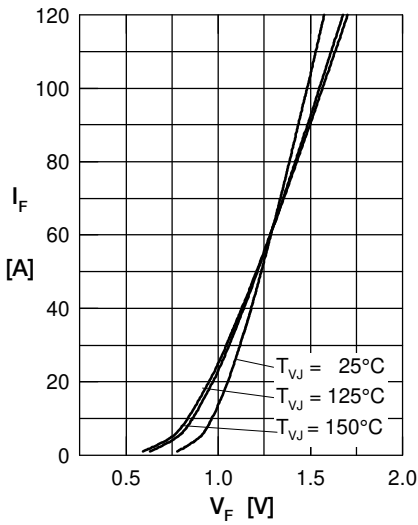


Fig. 1 Forward current versus voltage drop per diode

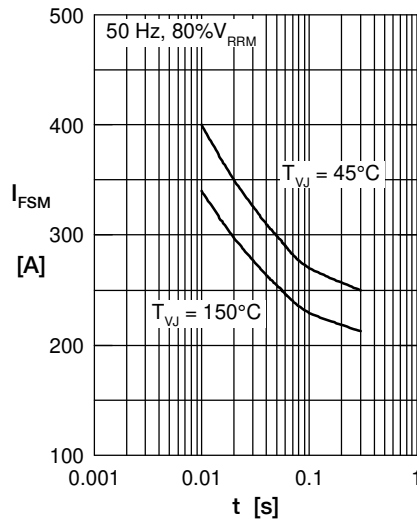


Fig. 2 Surge overload current vs. time per diode

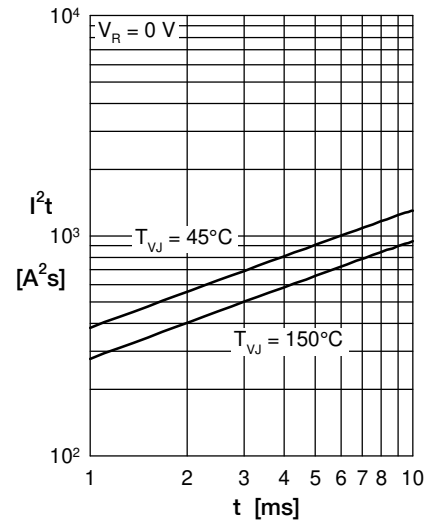


Fig. 3 I^2t versus time per diode

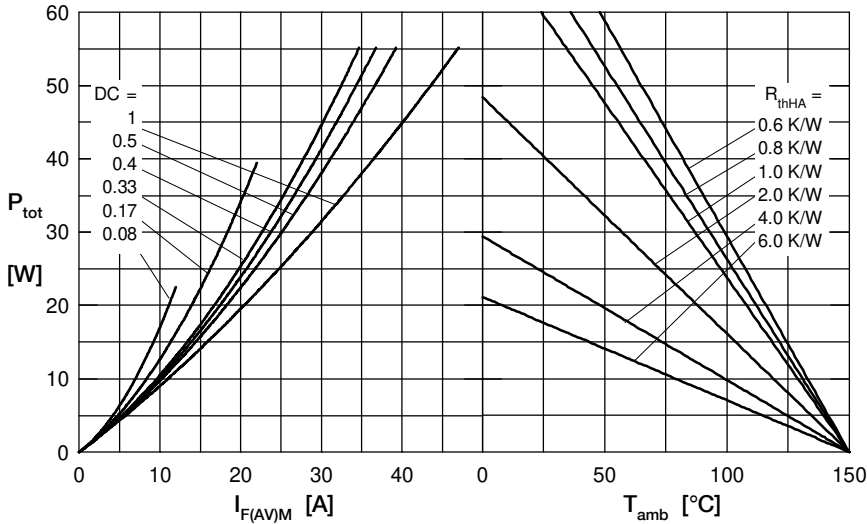


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

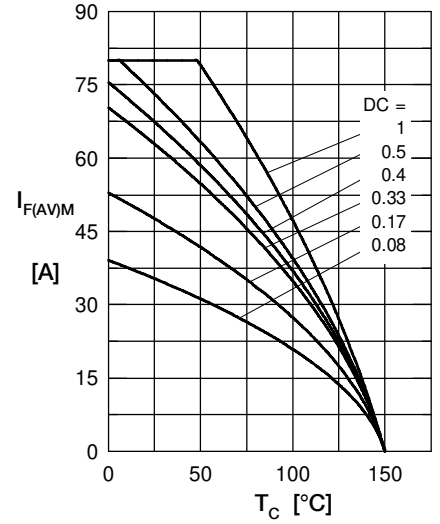


Fig. 5 Max. forward current vs. case temperature per diode

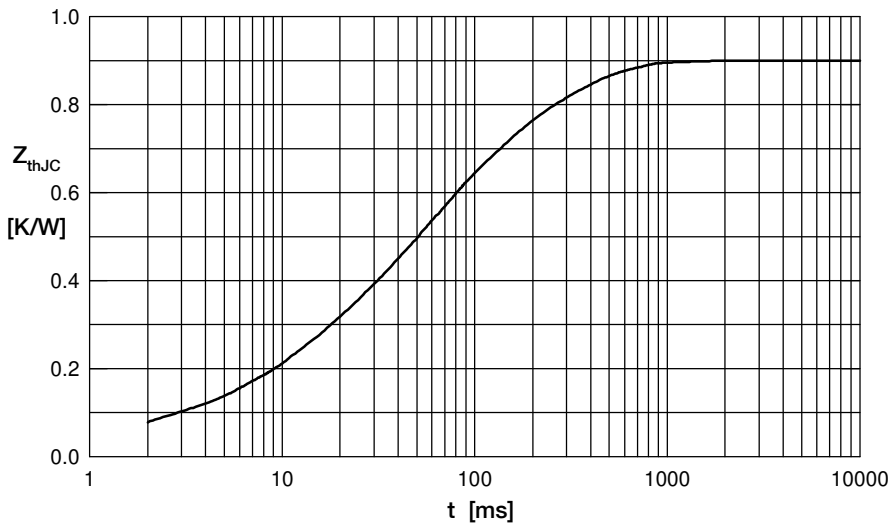


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.042	0.001
2	0.128	0.010
3	0.425	0.050
4	0.305	0.230